

1 DESCRIPTION

The MT5705 is an SoC (System on Chip) for magnetic induction based wireless power receiver.

It is fully compliant with the latest WPC Qi specification (Version 1.2.4) of BPP (Baseline Power Profile). It is capable of wireless charging for 5W of delivered power with fully programmable output voltage (maximum 10V) and current limit (maximum 1A).

MT5705 has a very high overall AC to DC conversion efficiency (larger than 90%), thanks to the optimized and adaptive full synchronous rectifier control, very small $R_{ds(on)}$ of power MOSFET's, and extremely low bias current.

With the exception of a few external passive components, this SoC integrates everything that is needed for a wireless power receiving function. It is composed of an ARM Cortex M0 processor with 2KB SRAM and 8KB OTP, full synchronous rectifier and special output LDO, robust and reliable over voltage, over current and over temperature protection circuits, bi-directional communication unit and various GPIO's and serial interfaces.

With the flexibility of SoC architecture and the unique implementation, the MT5705 is future proof in supporting WPC Qi specification's further updates and new proprietary protocols.

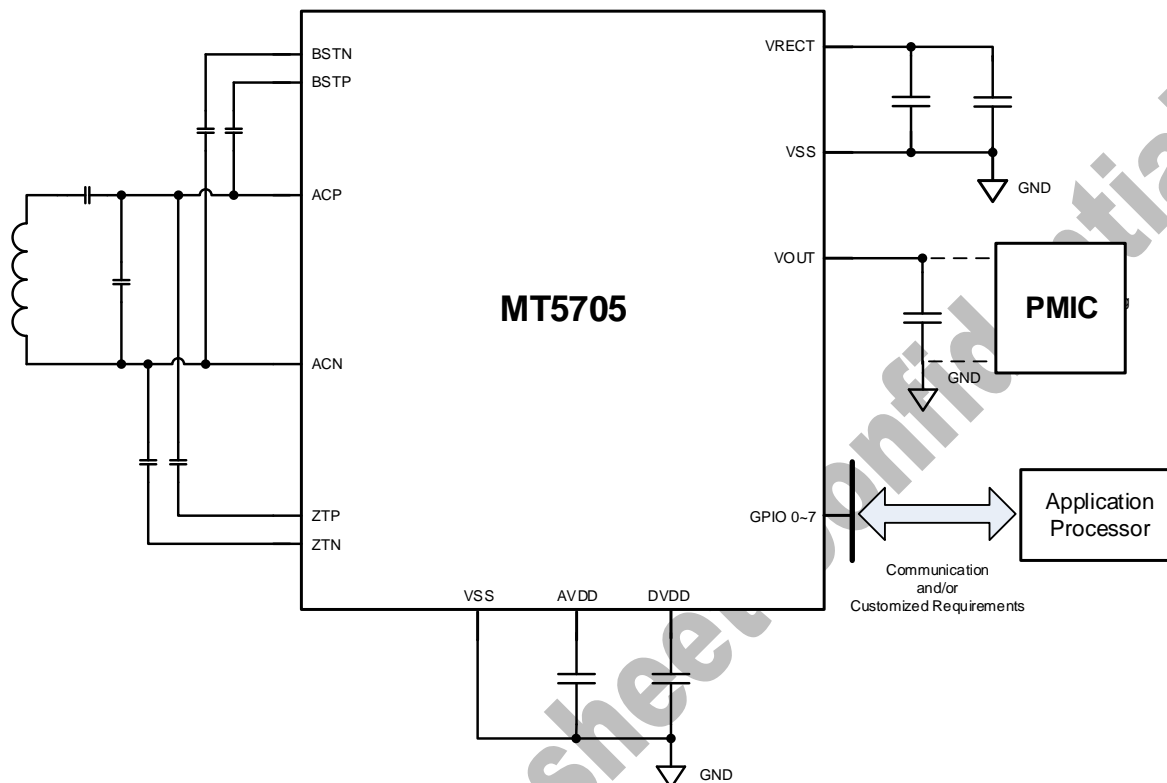
2 FEATURES

- 5W power delivery
- Fully programmable output voltage (up to 10V) and current limit (up to 1A)
- Embedded ARM Cortex M0 processor with 2KB SRAM and 8KB OTP
- Larger than 90% AC input to DC output efficiency
- Fully integrated bi-directional current sensing
- Reliable and unique over voltage, current, temperature protection
- Specially designed output LDO with output clamping and fast response to line and load transient
- WPC compliant and proprietary communication protocols support with hardware ASK and FSK modulation and demodulation
- Independent I2C slave and I2C master interface with additional GPIO's
- Available in 4.00mm x 4.00mm QFN32L package

3 APPLICATIONS

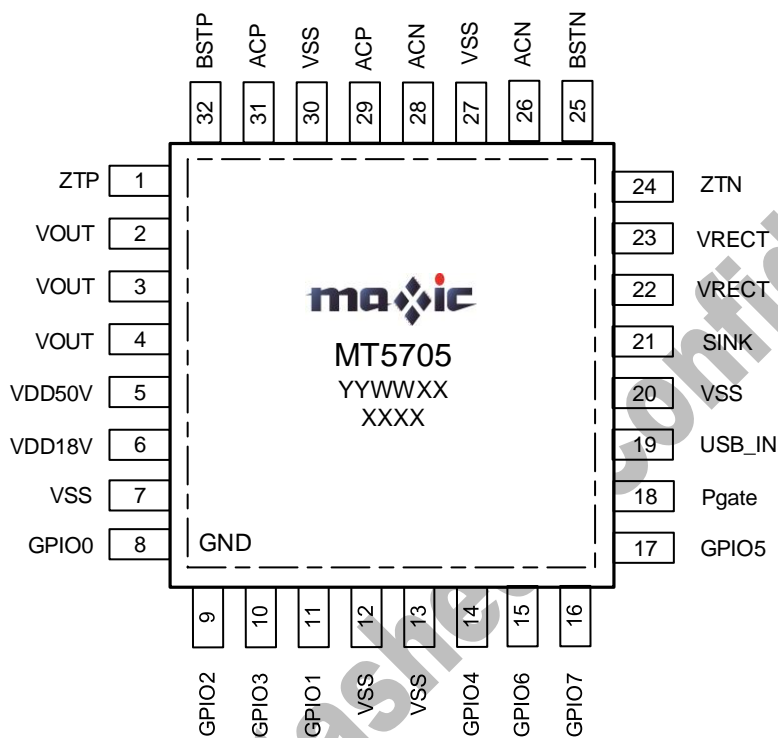
- Standard wireless charging for smart phones with 5W received power
- Wireless charging for wearable devices with high integration and small form factor
- Rx function for phones or power banks where they can be wirelessly charged
- Other wireless power applications

4 TYPICAL APPLICATION CIRCUIT



5 PIN CONFIGURATIONS AND FUNCTIONS

5.1 QFN32L Pin Configurations



5.2 Pin Functions

Pin Name	Pin No.	Description
ZTP	1	ASK Modulation FET at ACP.
VOUT	2, 3, 4	Output of LDO.
VDD50V	5	Internal 5V Power Supply.
VDD18V	6	Internal 1.8V Power Supply.
VSS	7, 12, 13, 20, 27, 30	Ground
Pgate	18	Gate control signal for external Over Voltage Protection P-MOSFET.
USB_IN	19	USB power input
SINK	21	Providing sinking current.
ACN	26, 28	AC input, connect to one end of the coil.
ACP	29, 31	AC input, connect to the other end of the coil.
GND	Thermal Pad	Power Ground.
VRECT	22, 23	Output of Synchronous Rectifier.
BSTP	32	Boost Capacitor for internal driver for synchronous bridge rectifier at ACP.
BSTN	25	Boost Capacitor for internal driver for synchronous bridge rectifier at ACP.
ZTN	24	ASK Modulation FET at ACN.
GPIO0~7	8, 11, 9, 10, 14, 17, 15, 16	General Purpose I/O. Type: Push/Pull. For more details, see Section 5.3.

5.3 I/O Pin Default Configurations

GPIO0~7	
GPIO0:	General GPIO, ADC
GPIO1:	General GPIO, ADC
GPIO2:	I ² C master SCL.
GPIO3:	I ² C master SDA.
GPIO4:	General GPIO, ADC. Note: Dedicated current sense
GPIO5:	General GPIO, ADC.
GPIO6:	General GPIO, Open Drain
GPIO7:	General GPIO, Open Drain
Note: GPIO0~7 can be re-configured upon customers' request.	

6 SPECIFICATIONS

6.1 Absolute Maximum Ratings

ACN, ACP, ZTP, ZTN	-0.3V to 16V
BSTP, BSTN	-0.3V to ACP+6V, ACN+6V
VRECT, SINK	-0.3V to 16V
VOUT	-0.3V to 16V
VDD50V	-0.3V to 6V
GPIO0~7	-0.3V to 6V
VDD18V	-0.3V to 2V
PGATE	-0.3V to 20V
USB_IN	-0.3V to 20V
Storage Temperature	-55°C to 150°C
Maximum Soldering Temperature(Reflow, Pb-Free)	260°C

6.2 ESD Ratings

Test Model	Pins	Ratings
HBM	All pins	(TBD) V
CDM	All pins	(TBD) V

6.3 Recommended Operating Conditions

Operating Temperature(Environment)	-40°C ~85°C
Operating Current (Iout)	0 ~ 1A
Operating Voltage (Vrect)	3.5V ~ 10V

6.4 Thermal Information (Package Thermal Data)

Junction to ambient ($R_{\theta JA}$)	50°C/W
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6.5 Electrical Characteristics

(Test conditions: $V_{RECT}=12V$, $T_A=25^{\circ}C$, unless otherwise stated.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Start-up (VDD pin)						
UVLO	Under Voltage Lockout	VRECT rising from 0V		2.95		V
U_{VLO_HYS}	Under Voltage Lockout Hysteresis	VRECT falling		200		mV
Supply Current						
I_q	Quiescent Current			6		mA
Bridge Rectifier						
Rds(on)	Rds(on) of Power MOSFETs			90		mΩ
Over-Voltage Protection						
V_{OVP_DC}	DC Over-Voltage Protection(programmable)	Rising voltage			16	V
LSB_Vovp	Least Significant Bitat OVP			500		mV
LDO						
VOUT	Output Voltage Regulation	Vrect = 8V, Iout = 0A		5		V
LSB_VOUT	Least Significant Bit when programming output voltage			25		mV
Programming_Range				3~10		V
ILimit_max	Output Current Limit				1	A
LSB_ILimit	Least Significant Bit when programming output current limit			25		mA
ADC						
N	Resolution			12		Bit
f_{Sample}	Sampling Rate			100		kS/s
Channel	Number of Channels			8		
Miscellaneous						
AVDD	AVDD Output Voltage			5		V
DVDD	DVDD Output Voltage			1.8		V
Digital I/O Pins						
GPIO2, GPIO3, GPIO6 GPIO7	HIGH Level Input Voltage V_{IH}		1.26			V
	LOW Level Input Voltage V_{IL}				0.54	V
	LOW Level Output Voltage V_{OL}			0		V
	LOW Level Output Current I_{OL}	Test at $V_{OL}=0.4V$	$2/8^{\circ}$			mA
	Analog Input Range			0~2.4		V
GPIO0, GPIO1, GPIO4 GPIO5	HIGH Level Input Voltage V_{IH}		3.5			V
	LOW Level Input Voltage V_{IL}				1.5	V
	HIGH Level Output Voltage V_{OH}			5		V
	LOW Level Output Voltage V_{OL}			0		V



	HIGH Level Output Current I_{OH}	Test at $V_{OH}=4V$	$2/8^{\text{①}}$			mA
	LOW Level Output Current I_{OL}	Test at $V_{OL}=0.4V$	$2/8^{\text{①}}$			mA
	Analog Input Range			0~5		V

Note①: Digital I/O pin output current can be programmed.

Preliminary Datasheet Confidential

6.6 Typical Operating Characteristics

The following performance characteristics were taken using MT5815 wireless power transmitter at $T_A=25^{\circ}\text{C}$, unless otherwise noted.

Figure 1. Efficiency vs. Output Load: $V_{\text{out}}=5\text{V}$

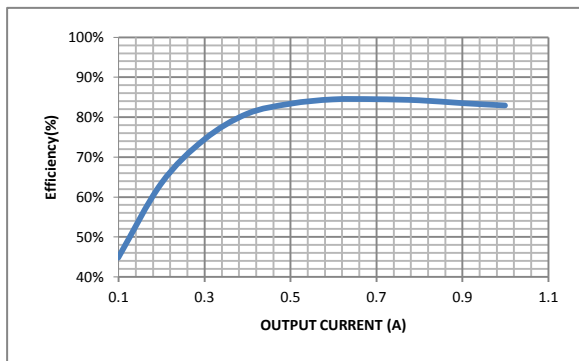


Figure 2. Load Reg. vs. Output Load: $V_{\text{out}}=5\text{V}$

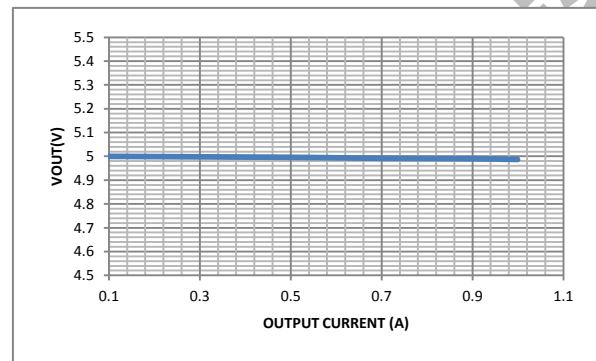
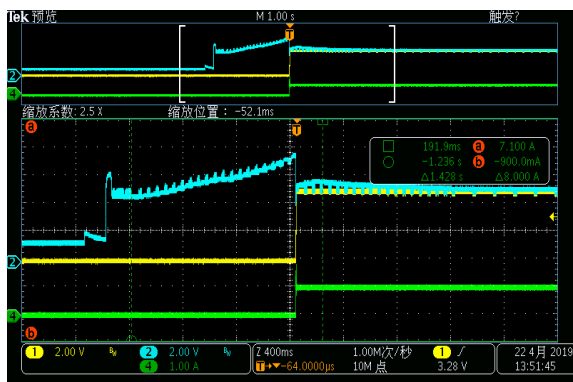


Figure 3. Enable Startup: $V_{\text{OUT}}=5\text{V}$; $I_{\text{OUT}}=1\text{A}$



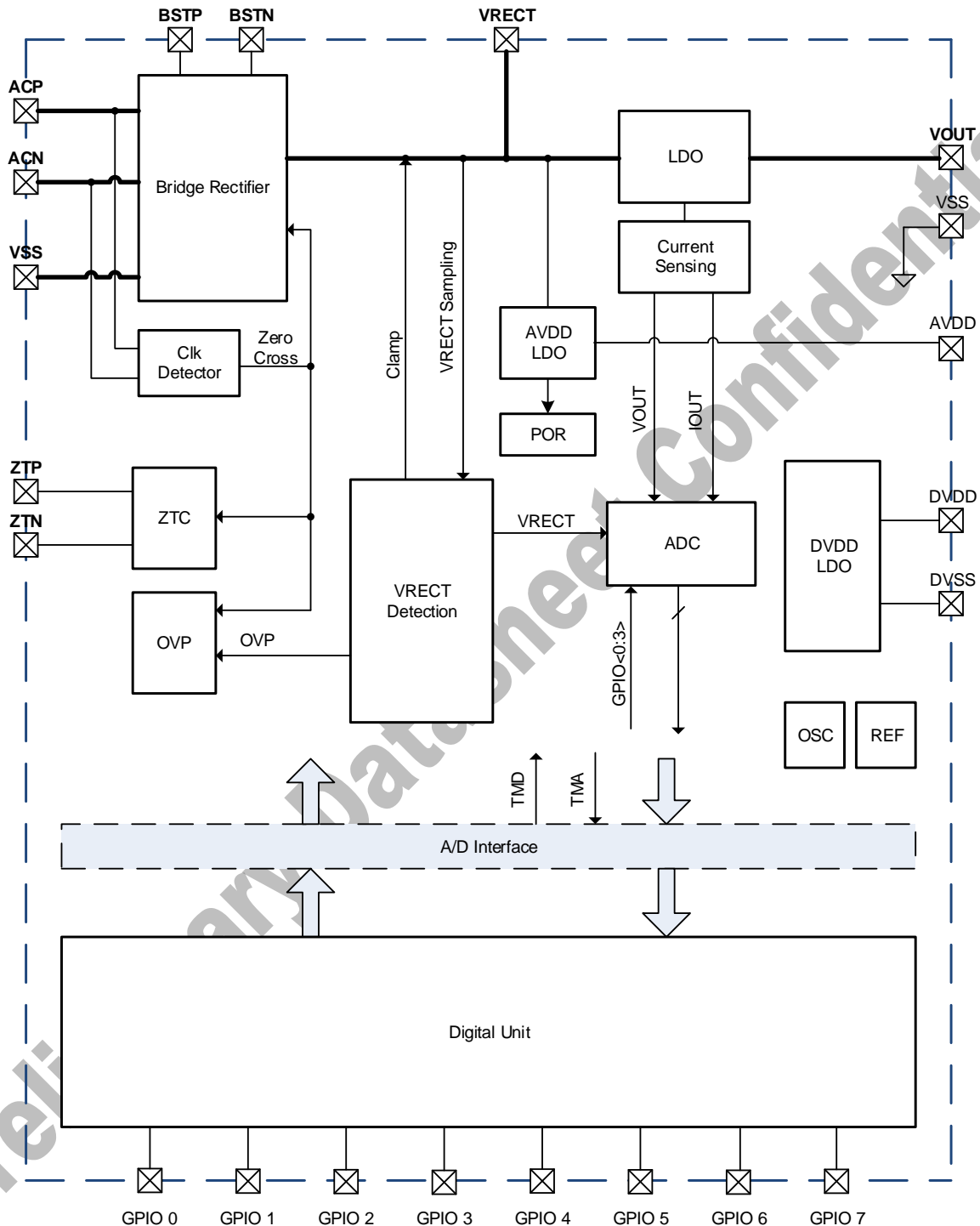
7 DETAILED DESCRIPTIONS

7.1 Overview

MT5705 is an SoC (System on Chip) for wireless power receiver. It only needs several passive components like power receiving coils, resonant tank capacitors, decoupling capacitors and pull up/down resistors to build a complete wireless power receiver system. When coupled with a wireless power transmitter, this system can provide all the functions for wireless power transfer, including power receiving and rectification, output regulation, communication for power control and data exchange, and abnormal condition (over voltage, current, temperature, etc.) protection.

MT5705 is by default programmed to be fully compliant with the latest WPC Qi Specification Version 1.2.4 with support of BPP (Baseline Power Profile).

7.2 Functional Block Diagram



7.3 Theory of Operation

MT5705 is composed of several major functional blocks which together achieve the wireless power receiving function.

Bridge Rectifier, which is also called Full Synchronous Rectifier. This block converts the received AC power from the resonant tank to DC power with the help of the capacitors connected on its output.

LDO, which is also called Main LDO or Output LDO. This block functions as a load switch (connecting and disconnecting the external load), output voltage and current regulation and output clamping when fast load/line transient happens.

AVDD and DVDD LDO and POR. These blocks provide the necessary regulated power supplies from rectifier output for the operation of the chip.

ZTC and CLK Detector. These blocks are for the bi-directional communication for power control and data exchange.

OVP and Vrect Detection. These blocks are for the rectifier output voltage detection and over voltage protection when Vrect is too high.

OSC and REF. These blocks provide the timing reference and voltage reference for the whole chip.

ADC. This block is one of the key blocks that convert various measured analog variables (voltages, currents, temperature, external analog inputs, etc.) to digital domain such that the embedded micro controller can use the information for follow up actions.

Digital Unit. This block contains all the digital circuits, which include embedded micro controller, volatile and nonvolatile memories, I2C interface, peripherals, DMA (Direct Memory Access), internal buses, and other digital functional blocks. This block is the brain of the whole chip which dynamically configures chip for different functions in different state, communicate with the outside world (power transmitter external host), and perform necessary data processing for proper operation (like target Vrect and Vout calculation, etc.)

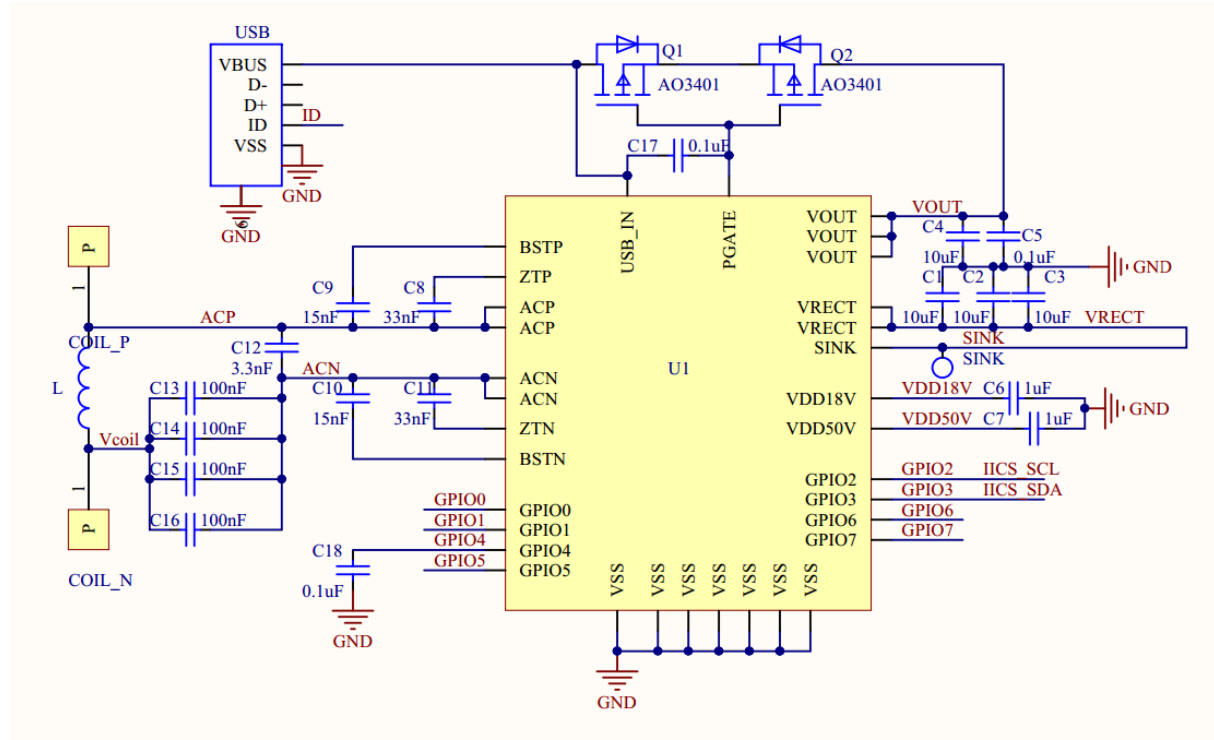
7.4 Device Function Modes

MT5705 can be programmed to operate in different modes. The switching among these modes can be made automatically based on the types of the transmitter or the instruction from the transmitter the receiver is coupled with. The operation modes can also be programmed by an external host (e.g., an Application Processor in a smart phone) via I2C interface. Here are some of these modes:

- WPC BPP only receiver mode
- WPC BPP and proprietary receiver mode
- WPC proprietary only receiver mode

8 APPLICATIONS AND IMPLEMENTATIONS

8.1 Reference Schematic

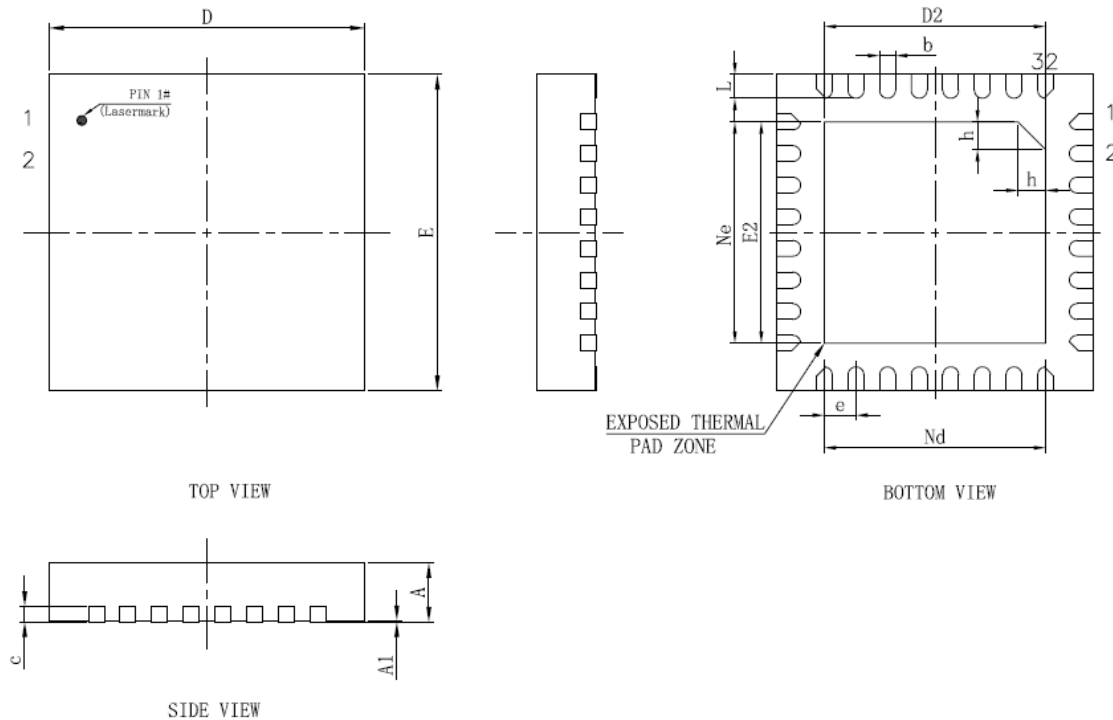


8.2 BOM

#	Reference	Value	Description	Footprint	Quanti
1	C1, C2, C3, C4	10uF	CAP CER 10UF 16V X7R 0603	0603	4
2	C5	0.1uF	CAP CER 0.1UF 16V X7R 0603	0603	1
3	C6, C7	1uF	CAP CER 1UF 6.3V X7R 0201	0201	2
4	C8, C11	33nF	CAP CER 0.033UF 25V X7R 0402	0402	2
5	C9,C10	15nF	CAP CER 0.015UF 25V X7R 0402	0402	2
6	C12	3.3nF	CAP CER 0.0033UF 25V X7R	0402	1
7	C13,C14,C15,C16	100nF	CAP CER 0.1UF 25V X7R 0603	0603	4
8	C17	0.1uF	CAP CER 0.1UF 16V X7R 0201	0201	1
9	C18	0.1uF	CAP CER 0.1UF 6.3V X7R 0201	0201	1
10	Q1,Q2	AO3401	P-channel MOSFET	SOT-23	2
11	U1	MT5705	Wireless power receiver	QFN32L	1
Notes					21


9 DETAILED PACKAGING INFORMATION

QFN32L Package Outline and Dimensions



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0	0.02	0.05
b	0.15	0.20	0.25
c	0.18	0.20	0.25
D	3.90	4.00	4.10
D2	2.70	2.80	2.90
e	0.40BSC		
Ne	2.80BSC		
Nd	2.80BSC		
E	3.90	4.00	4.10
E2	2.70	2.80	2.90
L	0.25	0.30	0.35
h	0.30	0.35	0.40
L/F	122X122		

10 ORDERING INFORMATION

Part No.	Package Type	Package Information	Package Quantity	Ambient Temperature	Chip Mark
MT5705	QFN32L	4.00 x 4.00mm QFN32L	3000	-40°C~+85°C	 MT5705 YYWWXX XXXX

11 REVISION HISTORY

Revision	Date	Description
1.0	2019-04-19	Preliminary version.

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